NSN 5961-00-497-4645

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-497-4645 **Inclosure Material:** Glass **Overall Length:** 0.510 millimeters **Terminal Length:** 0.260 millimeters **Overall Diameter:** 0.370 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.370 millimeters **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector to emitter, sustained and 60.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 150.00 milliamperes zero-gate-voltage source current blank **Power Rating Per Characteristic:** 800.0 watts small-signal input power, common-emitter absolute **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 175.0 degrees celsius case **Special Features:** High frequency low power silicon pnp bjt; junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No